Improvement of Carrier Power to Third-Order Intermodulation Distortion Power Ratio for a Power Amplifier at 5.25 GHz using LINC Method

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Abstract:

Introduction:
This paper focuses on improving the power amplifier linearity for wireless communications. The use of a single branch of a power amplifier can produce high distortion with low efficiency.

Method:
In this paper, the Linear Amplification with Nonlinear Components (LINC) technique is used to improve the linearity and efficiency of the power amplifier. The LINC technique is based on converting the envelope modulation signal into two constant envelope phase-modulated baseband signals. After amplification and combining the resulting signals, the required linear output signal is obtained. To validate the proposed approach, LINC technique is used for linearizing an amplifier based on a GaAs MESFET (described by an artificial neural network Model).

Conclusion:
Good results have been achieved, and an improvement of about 40.80 dBc and 47.50 dBc respectively is obtained for the Δlower C/I and Δupper C/I at 5.25 GHz.

Keywords: Carrier Power, Artificial Neural Network (ANN), Two Tones, Intermodulation Distortion IMD3, Carrier to intermodulation distortion power ratio (C/I), Linearization Techniques, LINC.

1. INTRODUCTION

In wireless communication systems, the Radio-Frequency (RF) Power Amplifiers (PAs) are one of the most critical components in designing transmitters. Recent trends in efficient and linear PA research have begun focusing more on the use of two-branched amplifier systems, than on the classical single-ended amplifier topology techniques [1]. The most popular dual-branch systems are the Doherty power amplifier [2]; the Envelope Elimination and Restoration (EER) technique and variations [3, 4]; the Linear Amplification with Nonlinear Components (LINC) technique [5]; and the modified implementation of the LINC concept (MILC) technique [6]. The outphasing power amplifier system was invented by Chireix [7] to improve the linearity and the efficiency of AM signal power amplifiers [8] invented the outphasing power amplifier system. The outphasing power amplifier is studied in [9].

The main idea behind the LINC technique consists of decomposing the envelope-varying input signal in two phase-modulated constant envelope signals. Each of which is amplified using an efficient and nonlinear amplifier. The

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combination of the amplified signals results in a linearly amplified output [10].

A popular technique of measuring the non-linearity of the amplifier is to find its carrier to intermodulation distortion power ratio (C/I), defined as the ratio of useful component output power and the Intermodulation Distortion (IMD) output power [11]. More than one carrier frequency is applied at the input of the amplifier; as a result, multiple sidebands (intermodulation products) are generated due to mixing behavior introduced by the non-linearity of the device. The IMD products are usually the third-order ones that occur at $2\omega_1 - \omega_2$ and $2\omega_2 - \omega_1$. They can’t be rejected by filters. The intermodulation is a major concern in microwave systems [12]. In real-world, amplifiers, due to several reasons, among which matching network components, output powers at the two fundamental frequencies and the third order intermodulation products in the upper and lower sidebands, can be different [13]. This means that the IMD at $2\omega_1 - \omega_2$ is different from the one at $2\omega_1 - \omega_2$ [14].

The design of a PA requires the designer to address several concurrent requirements on power efficiency and linearity. There exist several parameters which present a challenge during this design, such as the measurement of the Output Back-Off (OBO), the ACPR (Adjacent Channel Power Ratio), the Peak to Average Power Ratio (PAPR) and the Noise Power Ratio (NPR). In this present study, we choose the C/I ratio.

This article focuses on the LINC technique for the linearization of a power amplifier operating at 5.25 GHz. An ANN model based on real measurements describes the nonlinearity of the GaAs MESFET (MGF1923) transistor.

Results show an improvement of about 40.80 dBc and 47.50 dBc, respectively for the C/I ratio in the upper and lower sidebands. The layout of the final prototype is implemented.

2. DESIGN & IMPLEMENTATION OF THE POWER AMPLIFIER

2.1. Amplifier Design

The MGF1923 transistor operating at 5.25 GHz is used to design the power amplifier. The model of the transistor is based on an Artificial Neural Network (ANN-Model) described in detail in [15]. This approach allows for the modeling of the drain current with good accuracy, taking into account the effects of traps and self-heating, as well as other nonlinearities, such as capacities gate to source and gate to drain.

2.2. Single Tone Test

Single tone test determines some important characteristics of the power amplifier, like power gain, Power Added Efficiency (PAE), and Pout. Figs. (1a and 1b) illustrates the simulation results. The PAE can be defined as:

$$\text{PAE} = \frac{P_{RFout} - P_{RFin}}{P_{dc}}$$  \hspace{1cm} (1)

Where $P_{dc}$ is DC power.

![Fig. (1a). Simulated values for PAE.](image-url)
From this plot, we can see that the Power Added Efficiency (PAE) = 37.5%.

Fig. (1b). Simulated values for power gain and Pout.

From this plot, we can see that the $P_{1\text{dB}}$ compression input power is about 7.5 dBm and the output power is about 12.5 dBm, and the gain corresponding is about 5 dBm.

2.3. Two Tones test

The IMD3 is the measure of the third-order distortion produced by a nonlinear device. This distortion product is usually so close to the carrier that it can cause interference in multichannel communication equipment. The third order Intercept Point (IP3) or (TOI) are often used as figures of merit for IMD. IP3 is an important parameter for nonlinear systems which helps to verify the linearity of the device. It can be used to define the upper limit of the dynamic range of an amplifier.

Fig. (2) illustrates the Third-Order Intercept Point. We can see that the TOI is about 22 dBm.

Fig. (2). Simulated Third-Order Intercept Point (TOI).

Intermodulation distortion occurs when more than one input frequency is present in the circuit under evaluation. In this work, the two input frequencies are at $(5.25 \pm 0.005)$ GHz. The carrier to intermodulation ratio (C/I), defined as the ratio between useful output power ($P_{\text{RFout}}$) and IMD output power ($P_{\text{IMD}}$), can indicate the PA nonlinear behavior. It is usually measured, using logarithmic units, in decibels below the carrier (dBc):
\[ C/I = \frac{P_{RFout}}{P_{IMD}} \] (2)

The output spectrum of the power amplifier is shown in Fig. (3).

![Output spectrum with the two-tone test.](image)

The simulated upper and lower C/I at these conditions are 16.7 dBC and 14 dBC, respectively.

3. LINEAR AMPLIFICATION WITH NONLINEAR COMPONENTS (LINC)

LINC is a technique whereby a linear modulation signal is converted into two constant envelope signals that are independently amplified by power amplifiers and then combined using a coupler. The conventional architecture of this technique is depicted in Fig. (4). The splitter is used at the input to split signals and realize the phase shift between the carrier and peaking amplifying paths. Then we can combine these two amplified signals with a Wilkinson combiner to obtain the signal \( V_{out} \), which is a linear amplification of the input signal [16].

![Schematic of LINC system.](image)
The input signal can be described by the following equations:

$$v_i = V(t) \cos(\omega_c t + \varphi(t)) = \cos(\omega_c t + \varphi(t)) \cos(\arccos V(t))$$

(3)

Where $\omega_c$ is the Carrier angular frequency and $\varphi$ is the Carrier Phase.

At the outputs of the splitter, the input signal $v_i$ can be viewed as the sum of two signals $v_1$ and $v_2$ given by the following equations:

$$v_1 = \frac{1}{2} \cos(\omega_c t + \varphi(t) + \arccos V(t))$$
$$v_2 = \frac{1}{2} \cos(\omega_c t + \varphi(t) - \arccos V(t))$$

(4a)

(4b)

The signals $v_1$ and $v_2$ will be amplified by two nonlinear power amplifiers. The output amplified signals with the same voltage gain $A_v$ can be added to form the output voltage waveform.

The final output signal will be given by the following expression:

$$v_0 = A_v (v_1 + v_2) = A_v \left\{ \frac{1}{2} \cos(\omega_c t + \varphi(t) + \arccos V(t)) \right\}$$
$$+ \frac{1}{2} \cos(\omega_c t + \varphi(t) - \arccos V(t))$$

(5)

4. RESULTS AND DISCUSSION

The power amplifier is used to design the LINC system. For the input, the stabilization of the main and auxiliary device is fulfilled with a series resistor. Both the main and auxiliary amplifiers have been matched at the input and output respectively. The input signal is split into two signals and then combined using a coupler. The basic schematic of LINC system layout is reproduced in Fig. (7).

Fig. (5) illustrates the signals after linearization. The simulated upper and lower C/I at these conditions are 57.5 dBC and 61.5 dBC respectively. Fig. (6) illustrates the comparison of C/I before and after linearization.

![Fig. (5). Simulated IMD3 after linearization.](image-url)
Table 1 summarizes the results. We note a very good linearization. Δlower C/I and Δupper C/I are about 40.80 dBc and 47.50 dBc, respectively.

**Table 1. C/I ratio performances.**

<table>
<thead>
<tr>
<th>Carrier to Intermodulation Ratio (dBc)</th>
<th>Upper Carrier to Intermodulation Ratio (dBc)</th>
<th>Lower Carrier to Intermodulation Ratio (dBc)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Before LINC</td>
<td>16.7</td>
<td>14.00</td>
</tr>
<tr>
<td>After LINC</td>
<td>57.50</td>
<td>61.50</td>
</tr>
<tr>
<td>Linearization</td>
<td>Δupper C/I = 40.80</td>
<td>Δlower C/I = 47.50</td>
</tr>
</tbody>
</table>

**CONCLUSION**

In this paper, the design of a RF PA operating at 5.25 GHz has been presented. The PA delivered 12.5 dBm with 37.5% PAE and upper and lower C/I are 16.7 dBc and 14 dBc, respectively. In order to improve the PA linearity, the LINC technique is used. As a result of this method, we can reduce the Carrier Power to Third-Order Intermodulation...
Distortion Power Ratio. A very good linearization is obtained about 40.80 dBc for Δlower C/I and 47.50 dBc Δupper C/I.

CONSENT FOR PUBLICATION

Not applicable.

CONFLICT OF INTEREST

The authors declare no conflict of interest, financial or otherwise.

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